

#### VS-SD400N/R

Vishay Semiconductors

# Standard Recovery Diodes,

# (Stud Version), 400 A



- Wide current range
- High voltage ratings up to 2400 V
- · High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- · Compression bonded encapsulations
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



#### TYPICAL APPLICATIONS Converters

- Power supplies
- · Machine tool controls
- High power drives
- Medium traction applications

PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub> 400 A			
Package	DO-9 (DO-205AB)		
Circuit configuration	Single		

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		480	Α	
I <sub>F(AV)</sub>	T <sub>C</sub>	120	°C	
I <sub>F(RMS)</sub>		630		
	50 Hz	8250	Α	
IFSM	60 Hz	8640		
I <sup>2</sup> t	50 Hz	340	kA <sup>2</sup> s	
	60 Hz	311	KA-S	
V <sub>RRM</sub>	Range	1600 to 2400	V	
TJ		-40 to +190	°C	

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	WIBER VOLTAGE CODE VRRM, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V		V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA		
	16	1600	1700			
VS-SD400N/R	20	2000	2100	15		
	24	2400	2500			



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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		180° conduction, half sine wave		400	Α	
Maximum average forward current	I <sub>F(AV)</sub>			120	°C	
at case temperature				480	Α	
					100	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at 110	°C case tempe	rature	630	
		t = 10 ms	No voltage		8250	]
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	8640	Α
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		6940	
		t = 8.3 ms	reapplied		7270	
	l <sup>2</sup> t	t = 10 ms	No voltage		340	kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 8.3  ms	reapplied		311	
Maximum I-t for fusing		t = 10 ms	100 % V <sub>RRM</sub> reapplied		241	
		t = 8.3 ms			220	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		3400	kA <sup>2</sup> √s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < $I$ < $\pi$ x $I_{F(AV)}$ ), $I_J = I_J$ maximum		0.80	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.85		
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < $I$ < $\pi$ x $I_{F(AV)}$ ), $I_J = I_J$ maximum		0.55	- mW	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.51	ITIVV	
Maximum forward voltage drop	V <sub>FM</sub>	$I_{pk}$ = 1500 A, $T_J$ = $T_J$ maximum, $t_p$ = 10 ms sinusoidal wave		1.62	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	Tu		-40 to +190	°C
Maximum storage temperature range	T <sub>Stg</sub>		-55 to +200	
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	R <sub>thJC</sub> DC operation		K/W
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.04	r/vv
Maximum allowed mounting torque ± 10 %		Not-lubricated threads	27	Nm
Approximate weight			250	g
Case style		See dimensions (link at the end of datasheet	DO-9 (DO	-205AB)

$\Delta R_{thJC}$ CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.020	0.013		
120°	0.023	0.023		
90°	0.029	0.031	$T_J = T_J$ maximum	K/W
60°	0.042	0.044		
30°	0.073	0.074	]	

#### Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



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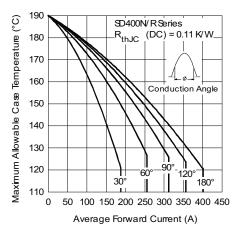


Fig. 1 - Current Ratings Characteristics

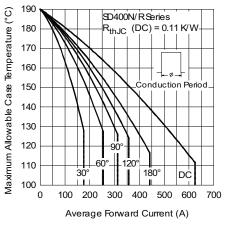


Fig. 2 - Current Ratings Characteristics

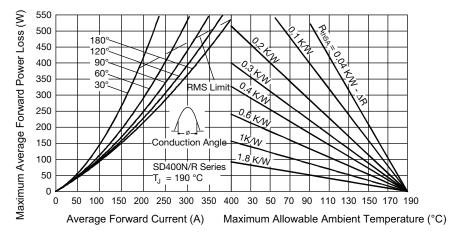


Fig. 3 - Forward Power Loss Characteristics

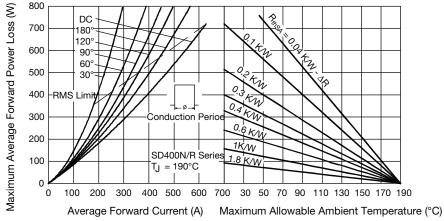


Fig. 4 - Forward Power Loss Characteristics



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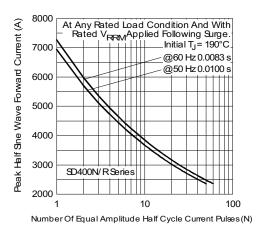


Fig. 5 - Maximum Non-Repetitive Surge Current

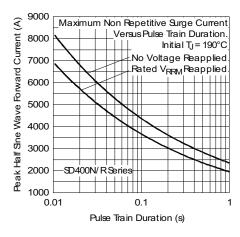


Fig. 6 - Maximum Non-Repetitive Surge Current

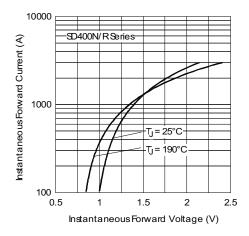


Fig. 7 - Forward Voltage Drop Characteristics

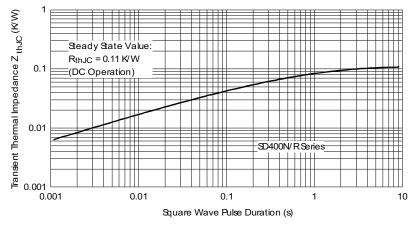


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristic

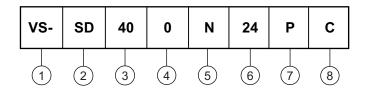


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#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Diode
  - Essential part number
- 4 0 = standard recovery
- 5 • N = stud normal polarity (cathode to stud)
  - R = stud reverse polarity (anode to stud)
- 6 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- 7 P = stud base DO-9 (DO-205AB) 3/4" 16UNF-2A
- 8 C = ceramic housing

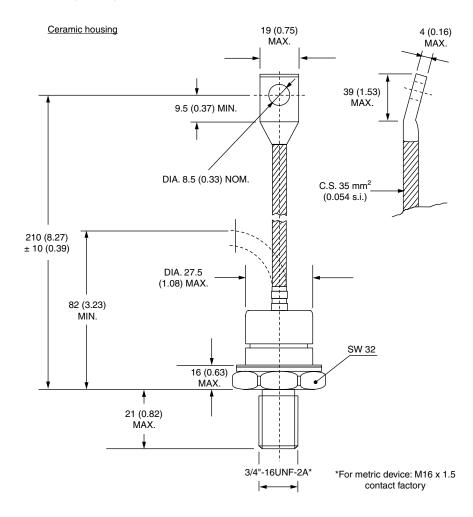
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95301		



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# **DO-205AB (DO-9)**

#### **DIMENSIONS** in millimeters (inches)





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